

Features

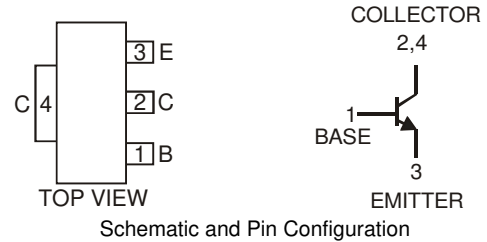
- Epitaxial Planar Die Construction
- Complementary PNP Type Available (DCX51)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- **Lead Free By Design/RoHS Compliant (Note 1)**
- **"Green" Device (Note 2)**



SOT89-3L

Mechanical Data

- Case: SOT89-3L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish — Matte Tin annealed over Copper leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking & Type Code Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.072 grams (approximate)



Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	45	V
Collector-Emitter Voltage	V_{CEO}	45	V
Emitter-Base Voltage	V_{EBO}	5	V
Peak Pulse Current	I_{CM}	1.5	A
Continuous Collector Current	I_C	1	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ $T_A = 25^\circ\text{C}$	P_D	1	W
Thermal Resistance, Junction to Ambient Air (Note 3) @ $T_A = 25^\circ\text{C}$	$R_{\theta JA}$	125	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_j, T_{STG}	-55 to +150	$^\circ\text{C}$

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Conditions	
OFF CHARACTERISTICS (Note 4)							
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	45	—	—	V	$I_C = 100\mu\text{A}, I_E = 0\text{A}$	
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	45	—	—	V	$I_C = 10\text{mA}, I_B = 0\text{A}$	
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	5	—	—	V	$I_E = 10\mu\text{A}, I_C = 0\text{A}$	
Collector Cut-off Current	I_{CBO}	—	—	100 20	nA μA	$V_{CB} = 30\text{V}, I_E = 0$ $V_{CB} = 30\text{V}, I_E = 0, T_A = 150^\circ\text{C}$	
Emitter Cut-off Current	I_{EBO}	—	—	100	nA	$V_{EB} = 5\text{V}, I_C = 0\text{A}$	
ON CHARACTERISTICS (Note 4)							
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	—	—	0.5	V	$I_C = 500\text{mA}, I_B = 50\text{mA}$	
Base-Emitter Turn-On Voltage	$V_{BE(ON)}$	—	—	1.0	V	$I_C = 500\text{mA}, V_{CE} = 2\text{V}$	
DC Current Gain	DCX54, DCX54-16	h_{FE}	63	—	—	—	$I_C = 5\text{mA}, V_{CE} = 2\text{V}$
			40	—	—	—	$I_C = 500\text{mA}, V_{CE} = 2\text{V}$
			63	—	250	—	$I_C = 150\text{mA}, V_{CE} = 2\text{V}$
	DCX54-16		100	—	250	—	$I_C = 150\text{mA}, V_{CE} = 2\text{V}$
SMALL SIGNAL CHARACTERISTICS							
Transition Frequency	f_T	—	200	—	MHz	$I_C = 50\text{mA}, V_{CE} = 5\text{V}, f = 100\text{MHz}$	
Output Capacitance	C_{obo}	—	—	15	pF	$V_{CB} = 10\text{V}, f = 1\text{MHz}$	

- Notes:
1. No purposefully added lead.
 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 3. Device mounted on FR-4 PCB; pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
 4. Measured under pulsed conditions. Pulse width = 300 μs . Duty cycle $\leq 2\%$.

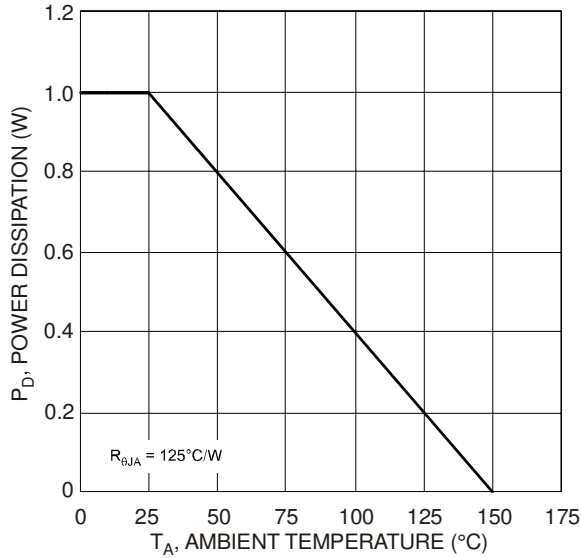


Fig. 1 Power Dissipation vs. Ambient Temperature (Note 3)

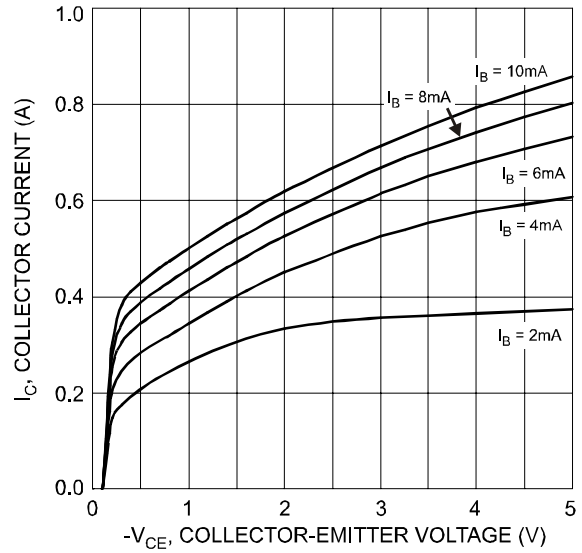


Fig. 2 Typical Collector Current vs. Collector-Emitter Voltage

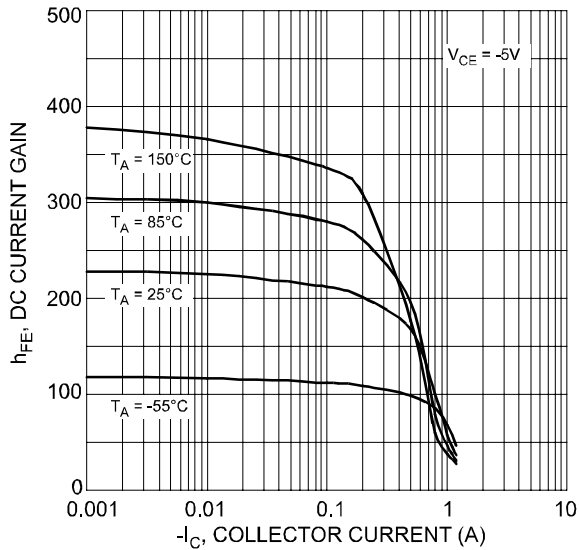


Fig. 3 Typical DC Current Gain vs. Collector Current

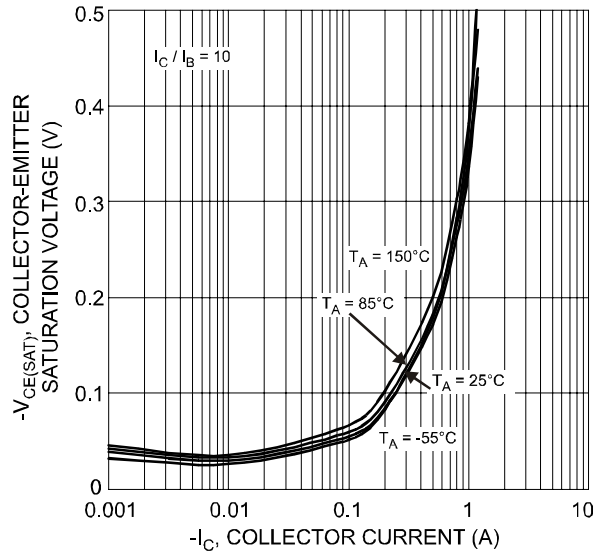


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

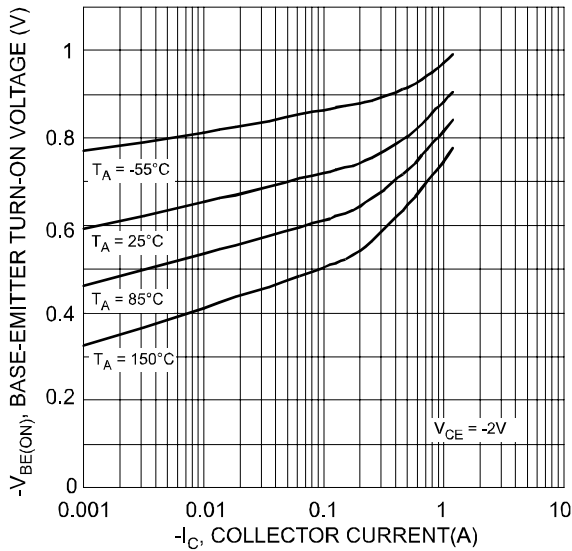


Fig. 5 Typical Base-Emitter Turn-On Voltage vs. Collector Current

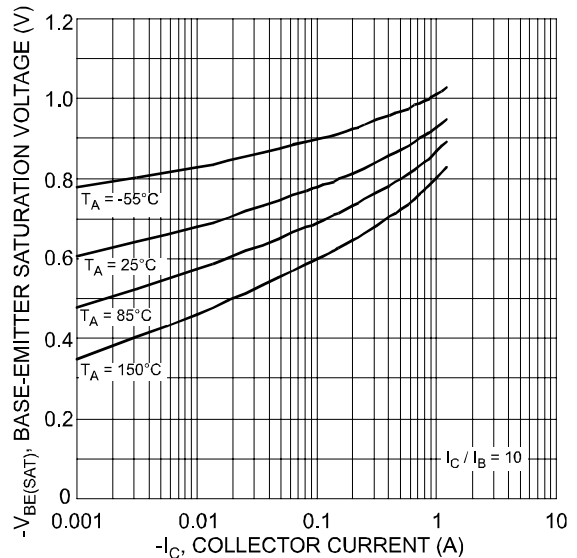
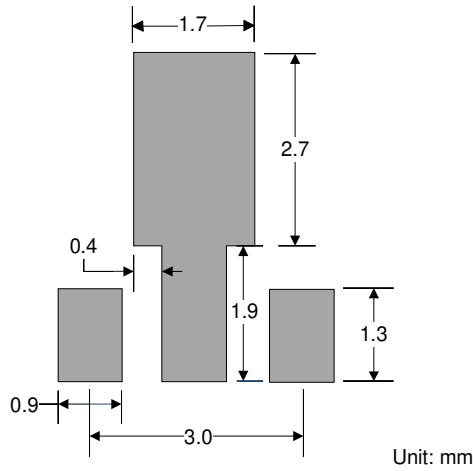


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

Suggested Pad Layout



Unit: mm

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